

TOSHIBA BIPOLAR DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

**TD62001P, TD62001AP, TD62001F, TD62001AF, TD62002P
TD62002AP, TD62002F, TD62002AF, TD62003P, TD62003AP, TD62003F
TD62003AF, TD62004P, TD62004AP, TD62004F, TD62004AF**

7CH DARLINGTON SINK DRIVER

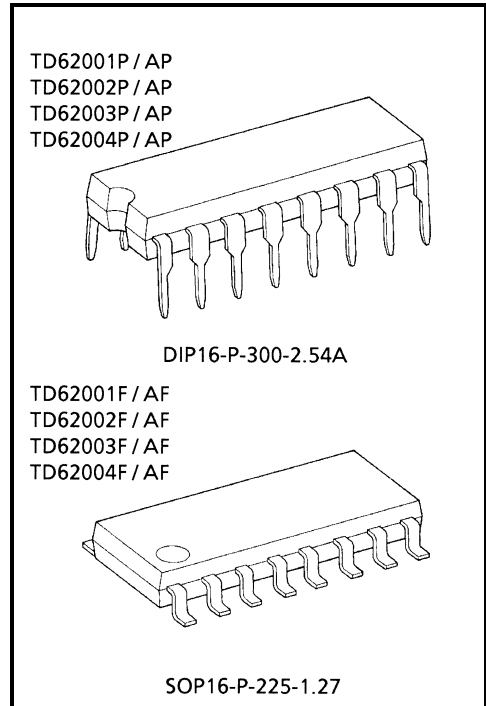
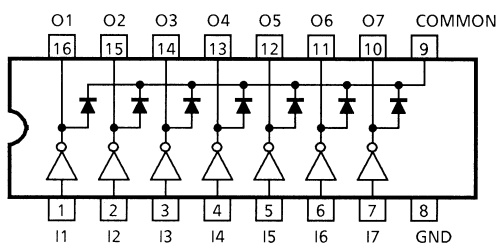
The TD62001P / AP / F / AF Series are high-voltage, high-current darlington drivers comprised of seven NPN darlington pairs. All units feature integral clamp diodes for switching inductive loads. Applications include relay, hammer, lamp and display (LED) drivers.

FEATURES

- Output current (single output) 500 mA MAX.
- High sustaining voltage output
35 V MIN. (TD62001P / F Series)
50 V MIN. (TD62001AP / AF Series)
- Output clamp diodes
- Inputs compatible with various types of logic
- Package Type-P, AP: DIP-16 pin
- Package Type-F, AF: SOP-16 pin

TYPE	INPUT BASE RESISTOR	DESIGNATION
TD62001P / AP / F / AF	External	General Purpose
TD62002P / AP / F / AF	10.5-k Ω + 7 V Zener diode	14~25 V PMOS
TD62003P / AP / F / AF	2.7 k Ω	TTL, 5 V CMOS
TD62004P / AP / F / AF	10.5 k Ω	6~15 V PMOS, CMOS

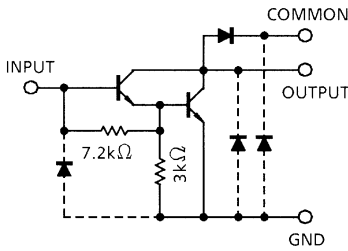
PIN CONNECTION (TOP VIEW)



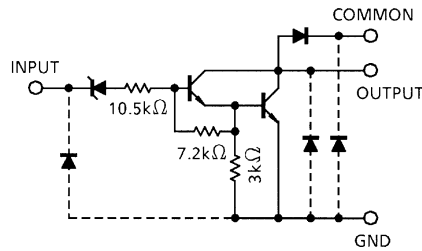
Weight
DIP16-P-300-2.54A : 1.11 g (Typ.)
SOP16-P-225-1.27 : 0.16 g (Typ.)

SCHEMATICS (EACH DRIVER)

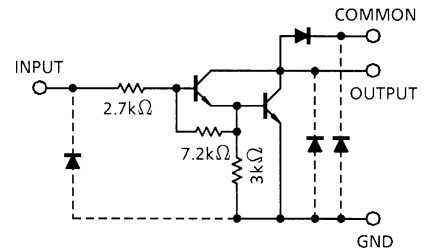
TD62001P / AP / F / AF



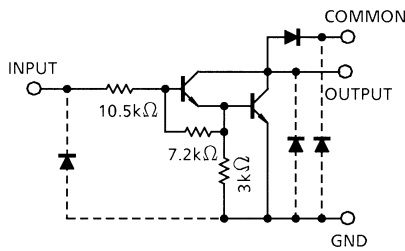
TD62002P / AP / F / AF



TD62003P / AP / F / AF



TD62004P / AP / F / AF



Note: The input and output parasitic diodes cannot be used as clamp diodes.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Output Sustaining Voltage	P, F	V _{CE (SUS)}	-0.5~35	V
	AP, AF		-0.5~50	
Output Current		I _{OUT}	500	mA / ch
Input Voltage		V _{IN (Note 1)}	-0.5~30	V
Input Current		I _{IN (Note 2)}	25	mA
Clamp Diode Reverse Voltage	P, F	V _R	35	V
	AP, AF		50	
Clamp Diode Forward Current		I _F	500	mA
Power Dissipation	P	P _D	1.0	W
	AP		1.47	
	F, AF		0.54 / 0.625 (Note 3)	
Operating Temperature	P	T _{opr}	-30~75	°C
	AP, F, AF		-40~85	
Storage Temperature		T _{stg}	-55~150	°C

Note 1: Except TD62001P / AP / F / AF

Note 2: Only TD62001P / AP / F / AF

Note 3: On glass epoxy PCB (30 × 30 × 1.6 mm Cu 50%)

RECOMMENDED OPERATING CONDITIONS

($T_a = -40\sim 85^\circ\text{C}$ and $T_a = -30\sim 75^\circ\text{C}$ for only Type-P)

CHARACTERISTIC		SYMBOL	CONDITION	MIN	TYP.	MAX	UNIT	
Output Sustaining Voltage	P, F	$V_{CE(SUS)}$		0	—	35	V	
	AP, AF			0	—	50		
Output Current	AP	I_{OUT}	$T_{pw} = 25\text{ ms}$ 7 Circuits $T_a = 85^\circ\text{C}$ $T_j = 120^\circ\text{C}$	Duty = 10%	0	—	370	mA / ch
				Duty = 50%	0	—	130	
	P			Duty = 10%	0	—	295	
				Duty = 50%	0	—	95	
	F, AF			Duty = 10%	0	—	233	
				Duty = 50%	0	—	70	
Input Voltage	Except TD62001P / AP / F / AF	V_{IN}		0	—	24	V	
Input Voltage (Output On)	TD62002	$V_{IN(ON)}$	$I_{OUT} = 400\text{ mA}$ $h_{FE} = 800$	14.5	—	24	V	
	TD62003			2.8	—	24		
	TD62004			6.2	—	24		
Input Voltage (Output Off)	TD62001	$V_{IN(OFF)}$		0	—	0.6	V	
	TD62002			0	—	7.4		
	TD62003			0	—	0.7		
	TD62004			0	—	1.0		
Input Current	Only TD62001	I_{IN}		0	—	10	mA	
Clamp Diode Reverse Voltage	P, F	V_R		—	—	35	V	
	AP, AF			—	—	50		
Clamp Diode Forward Current		I_F		—	—	350	mA	
Power Dissipation	P	P_D	$T_a = 85^\circ\text{C}$	—	—	0.6	W	
	AP			—	—	0.76		
	AF, F		$T_a = 85^\circ\text{C}$ (Note)	—	—	0.325		

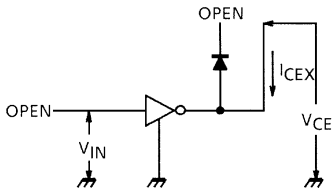
Note: On glass epoxy PCB (30 × 30 × 1.6 mm Cu 50%)

ELECTRICAL CHARACTERISTICS (Ta = 25°C unless otherwise noted)

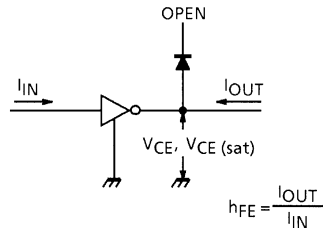
CHARACTERISTIC		SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN	TYP.	MAX	UNIT	
Output Leakage Current	AP, AF	I_{CEX}	1	$V_{CE} = 50\text{ V}, T_a = 25^\circ\text{C}$	—	—	50	μA	
				$V_{CE} = 50\text{ V}, T_a = 85^\circ\text{C}$	—	—	100		
	F			$V_{CE} = 35\text{ V}, T_a = 25^\circ\text{C}$	—	—	50		
				$V_{CE} = 35\text{ V}, T_a = 85^\circ\text{C}$	—	—	100		
	P			$V_{CE} = 35\text{ V}, T_a = 25^\circ\text{C}$	—	—	50		
				$V_{CE} = 35\text{ V}, T_a = 75^\circ\text{C}$	—	—	100		
Collector-Emitter Saturation Voltage		$V_{CE(sat)}$	2	$I_{OUT} = 350\text{ mA}, I_{IN} = 500\text{ }\mu\text{A}$	—	1.3	1.6	V	
				$I_{OUT} = 200\text{ mA}, I_{IN} = 350\text{ }\mu\text{A}$	—	1.1	1.3		
				$I_{OUT} = 100\text{ mA}, I_{IN} = 250\text{ }\mu\text{A}$	—	0.9	1.1		
DC Current Transfer Ratio		h_{FE}	2	$V_{CE} = 2\text{ V}, I_{OUT} = 350\text{ mA}$	1000	—	—		
Input Current (Output On)	TD62002	$I_{IN(ON)}$	3	$V_{IN} = 20\text{ V}, I_{OUT} = 350\text{ mA}$	—	1.1	1.7	mA	
	TD62003			$V_{IN} = 2.4\text{ V}, I_{OUT} = 350\text{ mA}$	—	0.4	0.7		
	TD62004			$V_{IN} = 9.5\text{ V}, I_{OUT} = 350\text{ mA}$	—	0.8	1.2		
Input Current (Output Off)	P	$I_{IN(OFF)}$	4	$I_{OUT} = 500\text{ }\mu\text{A}, T_a = 75^\circ\text{C}$	50	65	—	μA	
	AP, F, AF			$I_{OUT} = 500\text{ }\mu\text{A}, T_a = 85^\circ\text{C}$	50	65	—		
Input Voltage (Output On)	TD62002	$V_{IN(ON)}$	5	$V_{CE} = 2\text{ V}$ $h_{FE} = 800$	$I_{OUT} = 350\text{ mA}$	—	—	13.7	V
					$I_{OUT} = 200\text{ mA}$	—	—	11.4	
	TD62003				$I_{OUT} = 350\text{ mA}$	—	—	2.6	
					$I_{OUT} = 200\text{ mA}$	—	—	2.0	
	TD62004				$I_{OUT} = 350\text{ mA}$	—	—	4.7	
					$I_{OUT} = 200\text{ mA}$	—	—	4.4	
Clamp Diode Reverse Current	AP, AF	I_R	6	$V_R = 50\text{ V}, T_a = 25^\circ\text{C}$	—	—	50	μA	
				$V_R = 50\text{ V}, T_a = 85^\circ\text{C}$	—	—	100		
	F			$V_R = 35\text{ V}, T_a = 25^\circ\text{C}$	—	—	50		
				$V_R = 35\text{ V}, T_a = 85^\circ\text{C}$	—	—	100		
	P			$V_R = 35\text{ V}, T_a = 25^\circ\text{C}$	—	—	50		
				$V_R = 35\text{ V}, T_a = 75^\circ\text{C}$	—	—	100		
Clamp Diode Forward Voltage		V_F	7	$I_F = 350\text{ mA}$	—	—	2.0	V	
Input Capacitance		C_{IN}	—		—	15	—	pF	
Turn-On Delay	P, F	t_{ON}	8	$V_{OUT} = 35\text{ V}, R_L = 87.5\text{ }\Omega$ $C_L = 15\text{ pF}$	—	0.1	—	μs	
	AP, AF			$V_{OUT} = 50\text{ V}, R_L = 125\text{ }\Omega$ $C_L = 15\text{ pF}$	—	0.1	—		
Turn-Off Delay	P, F	t_{OFF}	8	$V_{OUT} = 35\text{ V}, R_L = 87.5\text{ }\Omega$ $C_L = 15\text{ pF}$	—	0.2	—		
	AP, AF			$V_{OUT} = 50\text{ V}, R_L = 125\text{ }\Omega$ $C_L = 15\text{ pF}$	—	0.2	—		

TEST CIRCUIT

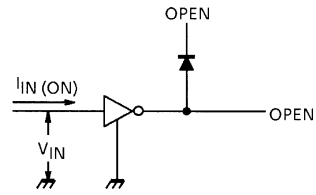
1. I_{CEX}



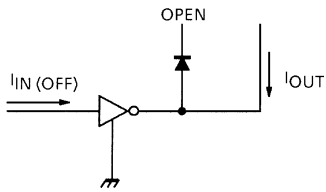
2. $V_{CE} (sat)$, h_{FE}



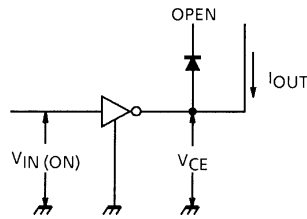
3. $I_{IN} (ON)$



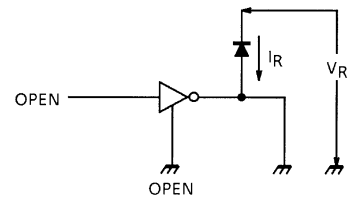
4. $I_{IN} (OFF)$



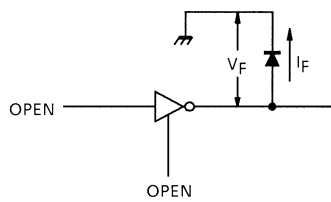
5. $V_{IN} (ON)$



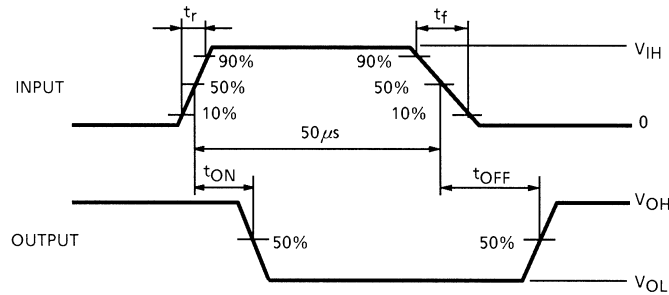
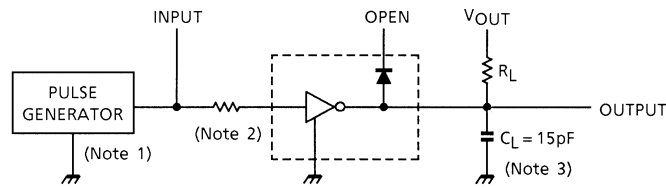
6. I_R



7. V_F



8. t_{ON} , t_{OFF}



- Note 1: Pulse width 50 μ s, duty cycle 10%
Output impedance 50 Ω , $t_r \leq 5$ ns, $t_f \leq 10$ ns
- Note 2: See below

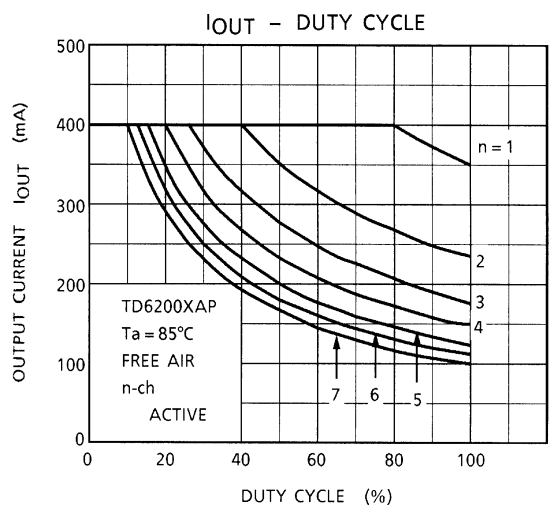
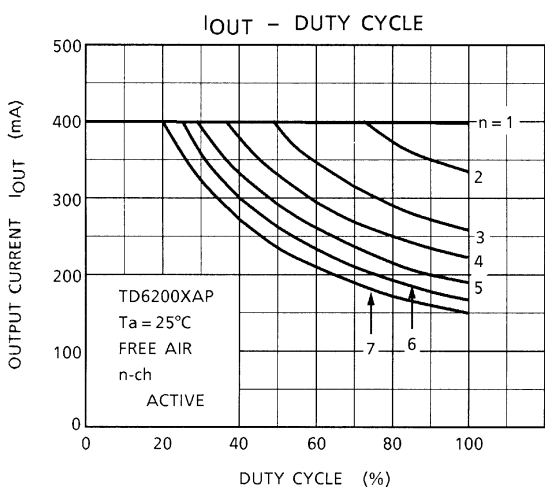
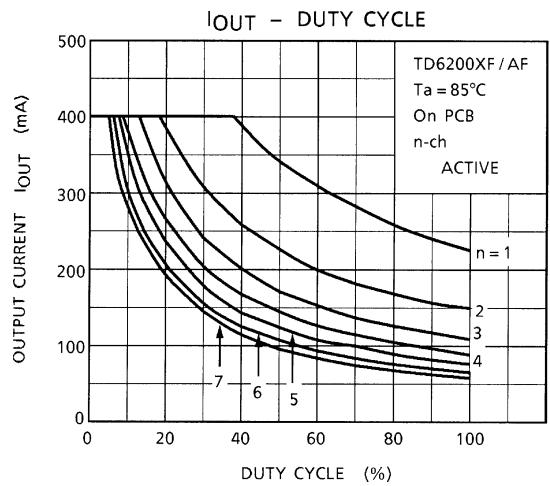
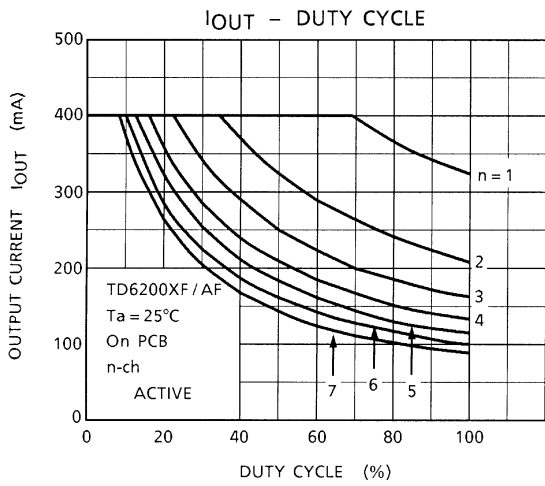
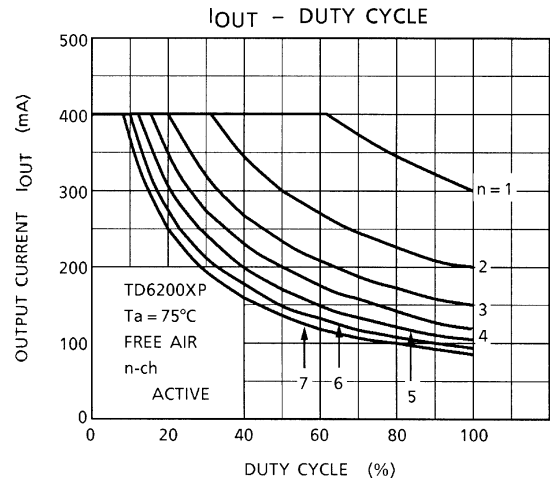
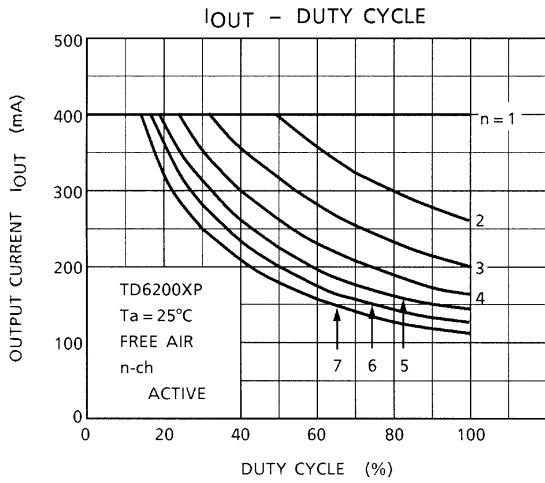
INPUT CONDITION

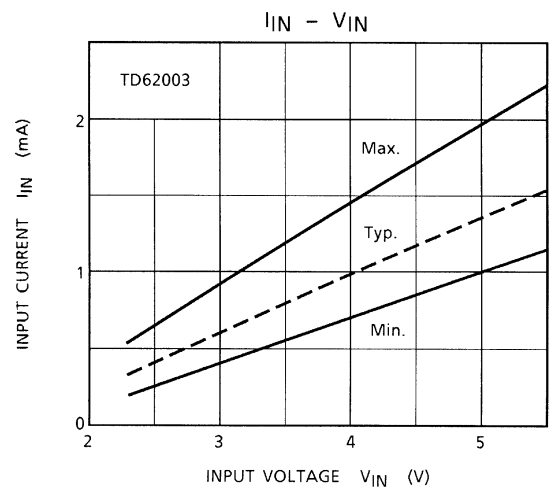
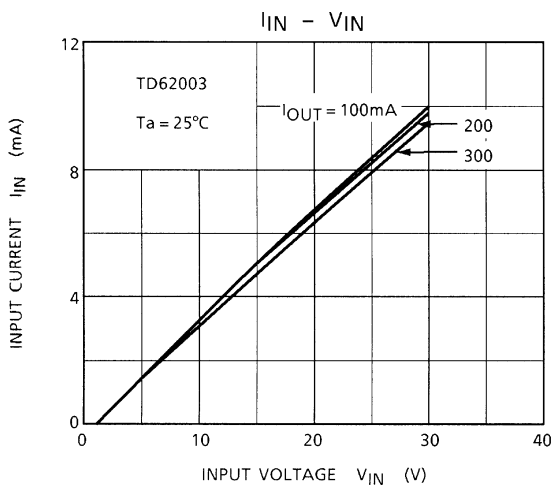
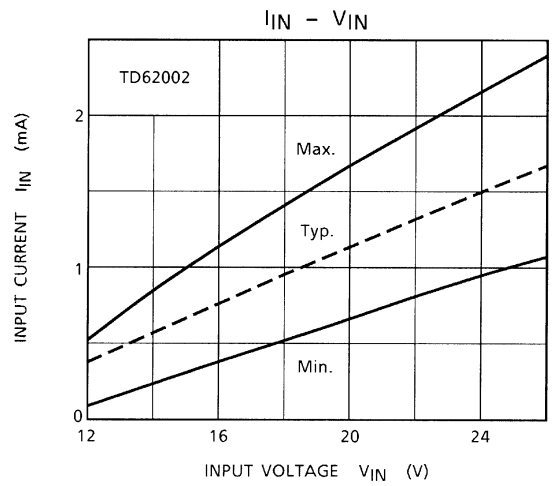
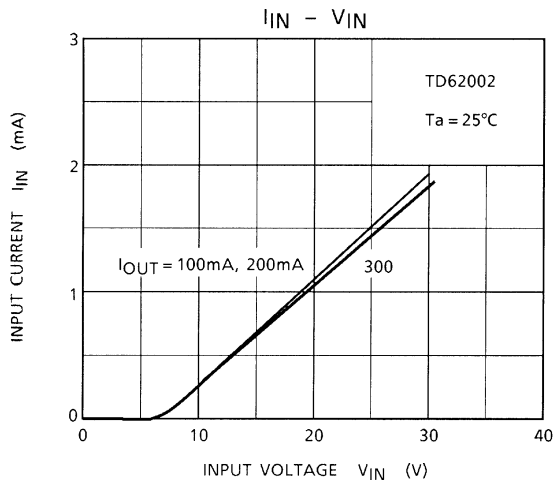
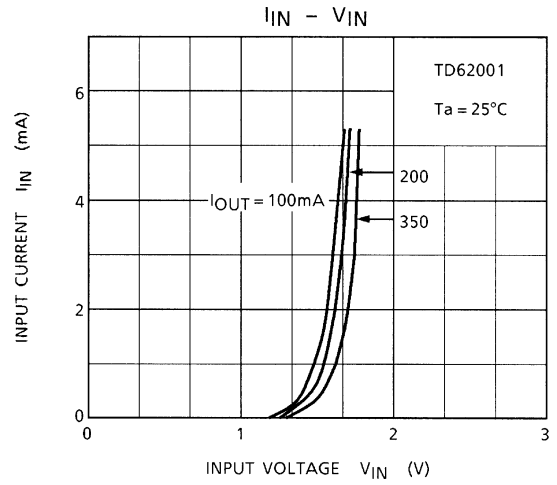
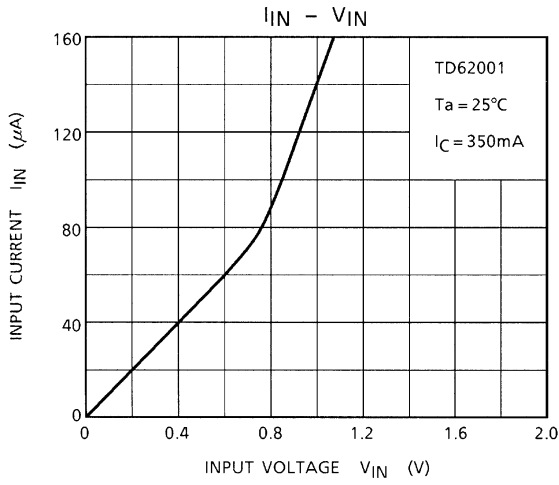
TYPE NUMBER	R1	V _{IH}
TD62001P / AP / F / AF	2.7 k Ω	3 V
TD62002P / AP / F / AF	0	13 V
TD62003P / AP / F / AF	0	3 V
TD62004P / AP / F / AF	0	8 V

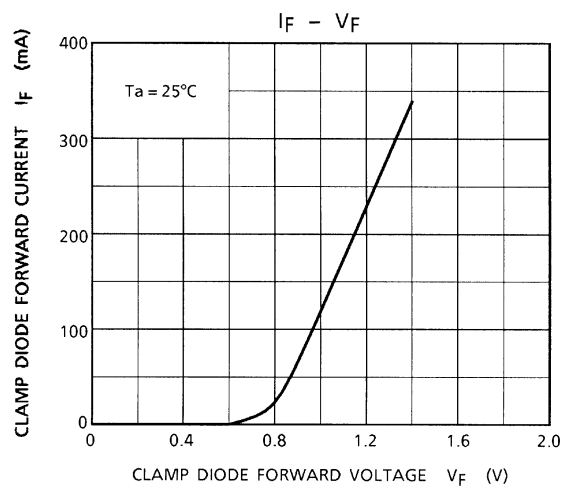
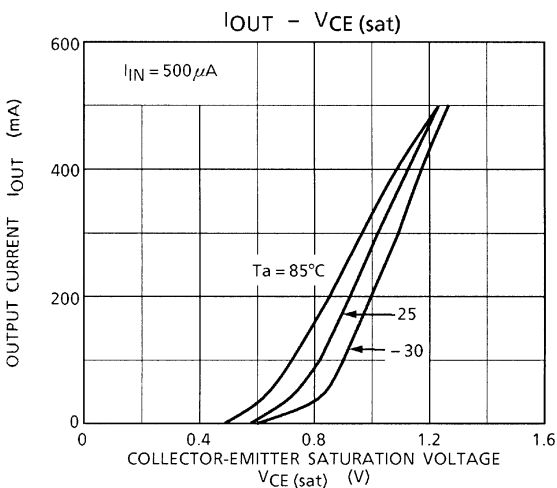
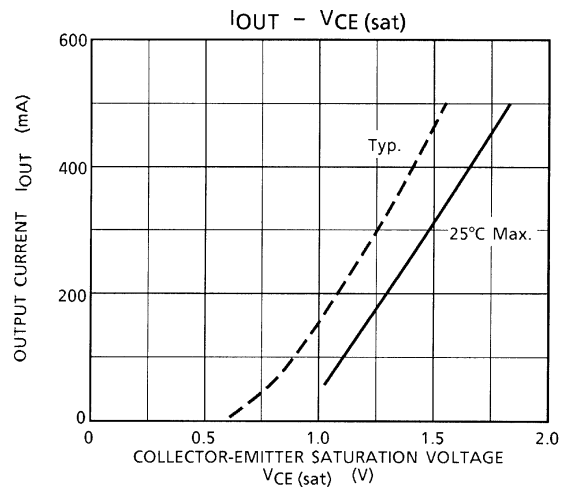
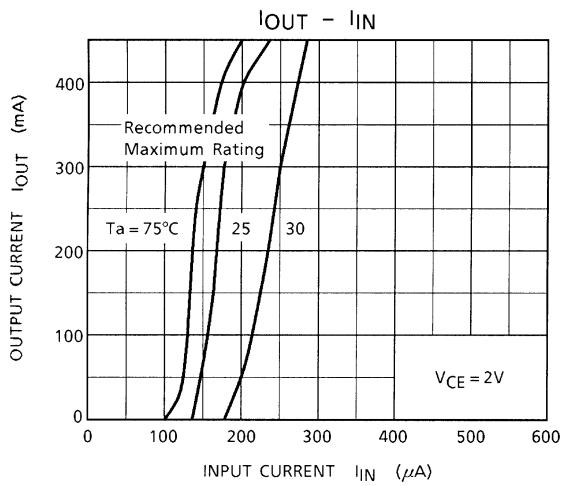
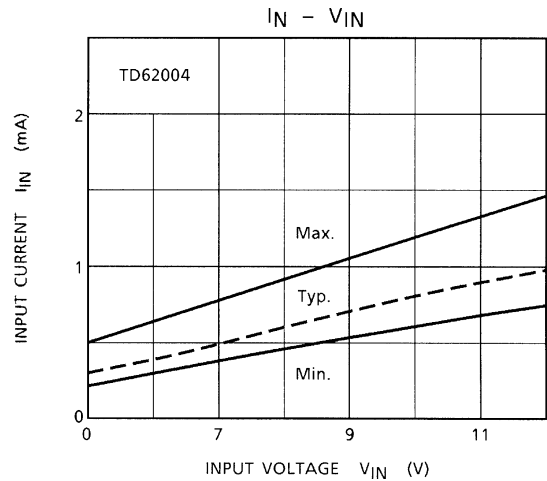
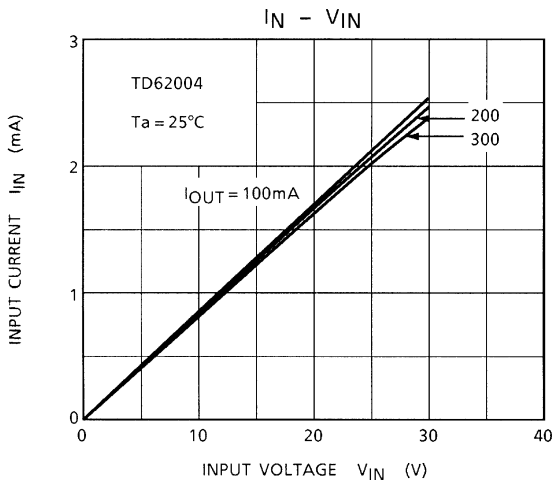
Note 3: C_L includes probe and jig capacitance.

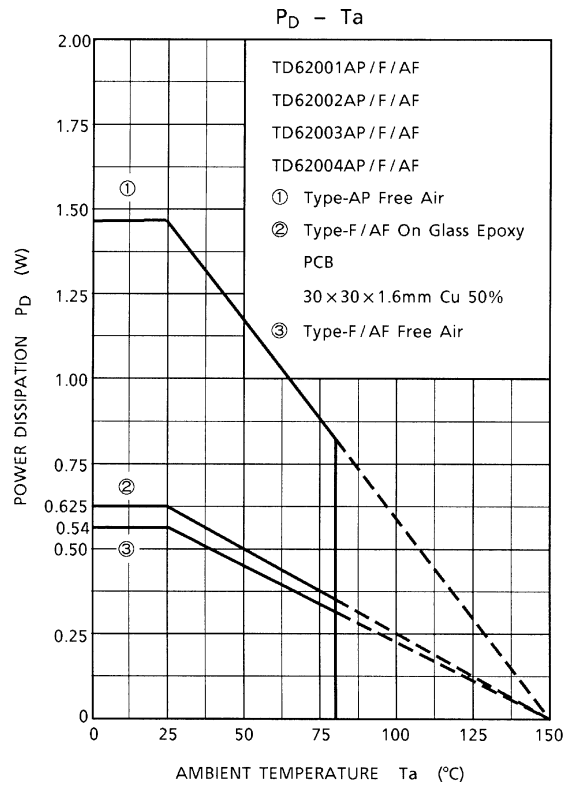
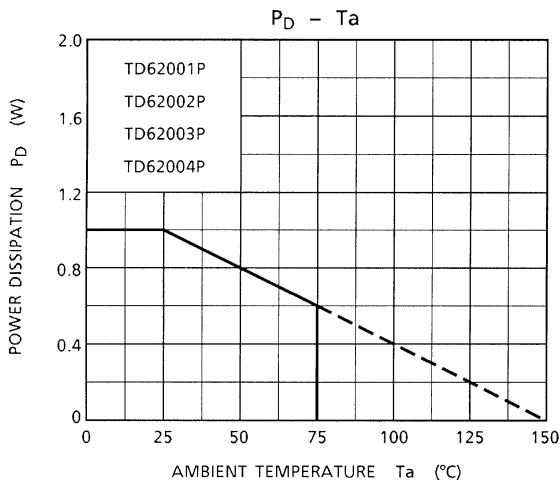
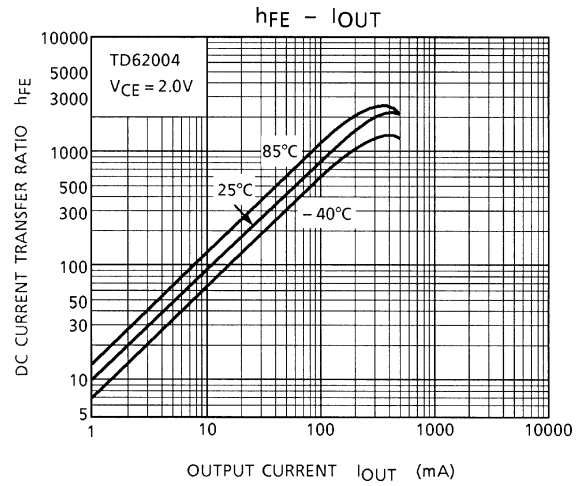
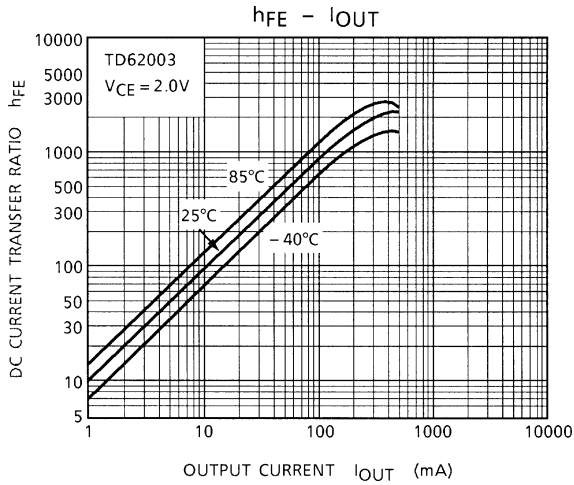
PRECAUTIONS for USING

This IC does not include built-in protection circuits for excess current or overvoltage. If this IC is subjected to excess current or overvoltage, it may be destroyed. Hence, the utmost care must be taken when systems which incorporate this IC are designed. Utmost care is necessary in the design of the output line, COMMON and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.





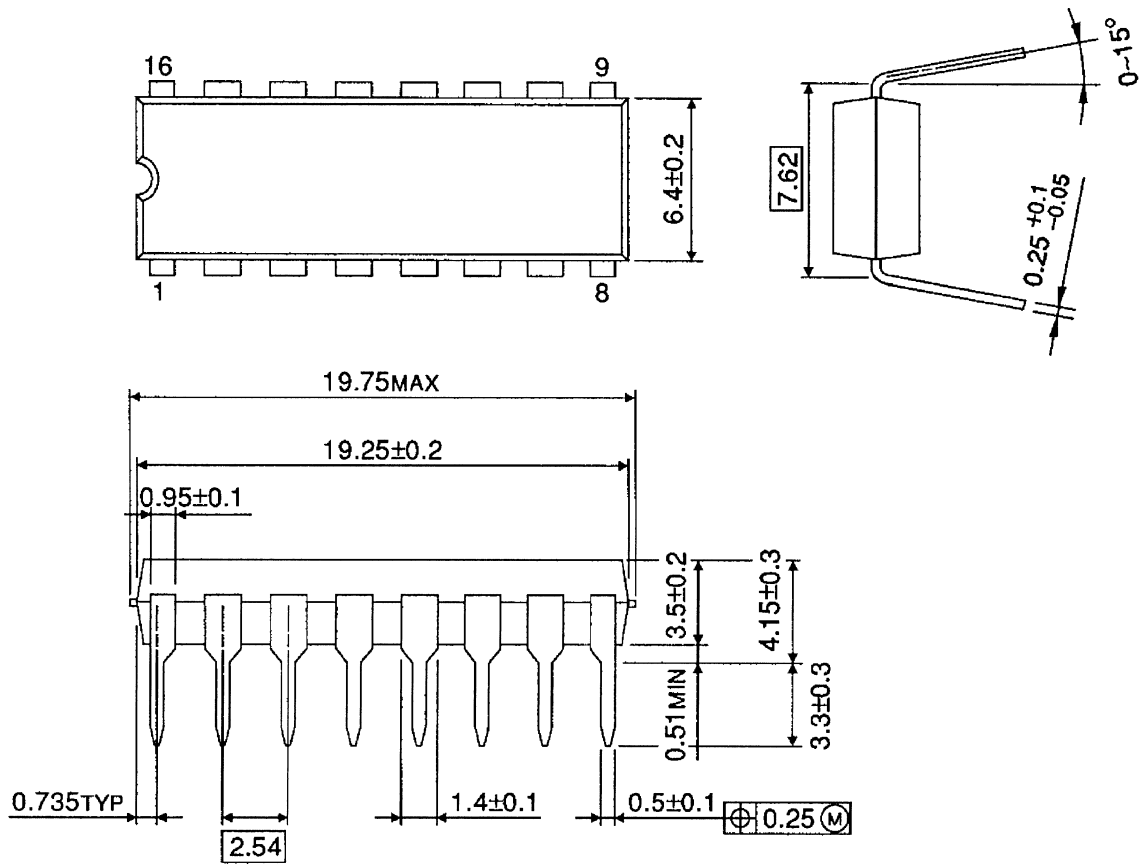




PACKAGE DIMENSIONS

DIP16-P-300-2.54A

Unit : mm

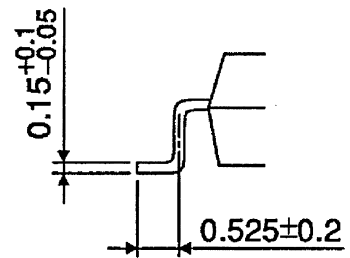
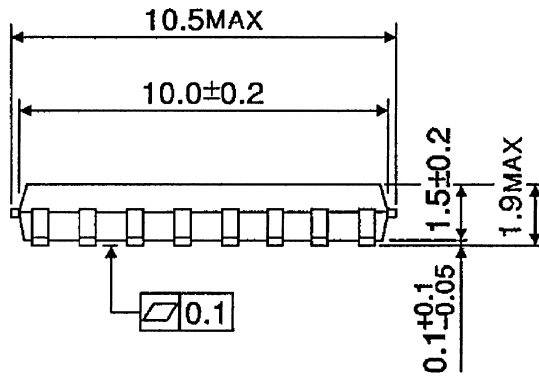
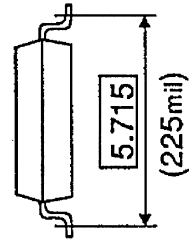
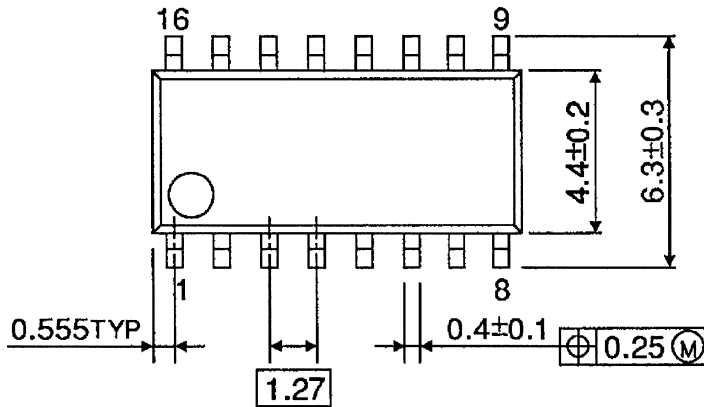


Weight: 1.11 g (Typ.)

PACKAGE DIMENSIONS

SOP16-P-225-1.27

Unit : mm



Weight: 0.16 g (Typ.)

RESTRICTIONS ON PRODUCT USE

000707EBA

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